Linear IC Converter

CMOS

D/A Converter for Digital Tuning

(12-channel, 8-bit, on-chip OP amp, low-voltage)

MB88346L

■ DESCRIPITON

The Fujitsu MB88346L is an 8-bit D/A converter capable of low-voltage operation, and designed with a built-in amp on each of its 12 analog output lines for large-current drive capability.

The use of serial data input means that only three control lines are required, and enables cascade connection of multiple MB88346L chips.

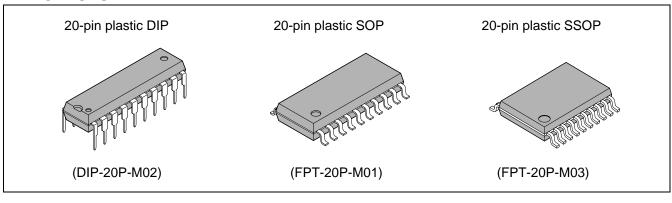
The MB88346L is suitable for applications such as electronic volume controls and replacement of semi-fixed resistors in tuning systems.

In addition, the MB88346L is both function-compatible and pin-compatible with the MB88346B now in use, allowing easy substitution of the MB88346L for reduced supply voltage.

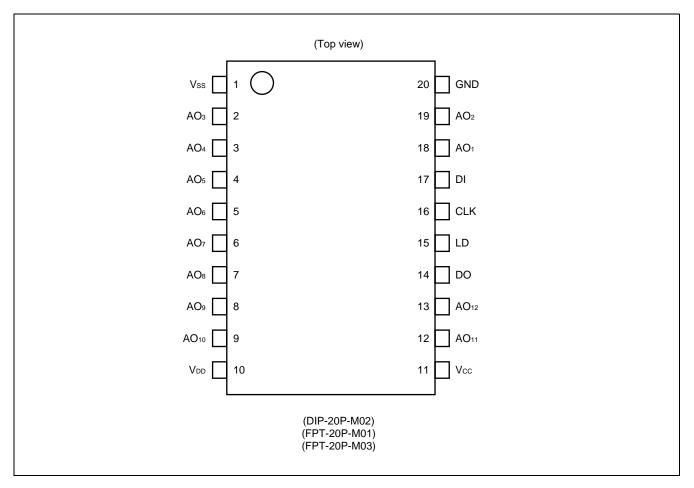
■ FEATURES

- Low voltage operation (Vcc/Vpd: 2.7 to 3.6 V)
- Ultra-low power consumption (0.5 mW/ch at Vcc = 3 V)
- Ultra-compact space-saving package lineup (SSOP-20)
- Contains 12-channel R-2R type 8-bit D/A converter
- On-chip analog output amps (sink current max. 1.0 mA, source current max. 1.0 mA)
- Analog output range from 0 to Vcc
- Two separate power supply/ground lines for MCU interface block/operational amplifier output buffer block and D/A converter block
- Serial data input, maximum operating speed 2.5 MHz
- (maximum operating speed in cascade connection is 1.5 MHz)
- CMOS process
- Package lineup includes DIP 20-pin, SOP 20-pin, SSOP 20-pin.

■ PACKAGES



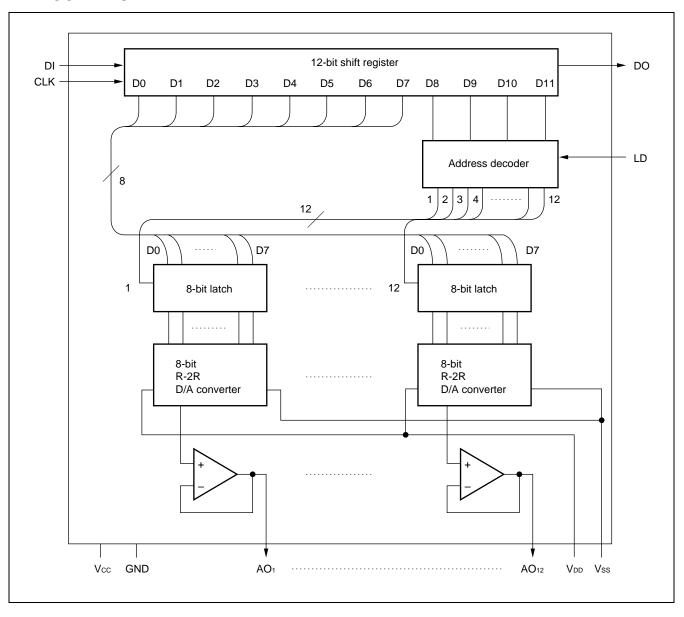
■ PIN ASSIGNMENT



■ PIN DESCRIPTION

| Pin No. | Symbol | I/O | Function |
|--|---|-----|--|
| 17 | DI | I | Serial address/data input to the internal 12-bit shift register: The address/data format is that upper 4 bits (D11 to D8) indicate an address and lower 8 bits (D7 to D0) indicate data. The D11 (MSB) is the first-in bit and D0 (LSB) is the last-in bit. |
| 14 | DO | 0 | Outputs MSB bit data from 12-bit shift register. |
| 16 | CLK | I | Shift clock input to the internal 12-bit shift register: At the rising edge of CLK data on the DI pin is shifted into the LSB of the shift register and contents of the shift register are shifted right (to the MSB). |
| 15 | LD | I | Load strobe input for a 12-bit address/data: A high level on the LD pin latches a 4-bit address (upper 4 bits: D11 to D8) of the internal 12-bit shift register into the internal address decoder, and writes 8-bit data (lower 8 bits: D7 to D0) of the shift register into an internal data latch selected by the latched address. |
| 18 19 2 3 4 5 6 7 8 9 12 13 | AO1 AO2 AO3 AO4 AO5 AO6 AO7 AO8 AO9 AO10 AO11 | 0 | 8-bit D/A output pins with OP amps. |
| 11 | Vcc | _ | MCU interface and OP amp power supply pin. |
| 20 | GND | _ | MCU interface and OP amp ground pin. |
| 10 | Vdd | | D/A converter power supply pin. |
| 1 | Vss | | D/A converter ground pin. |

■ BLOCK DIAGRAM

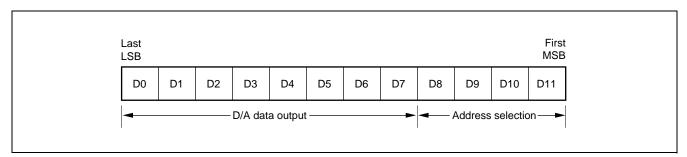


■ DATA CONFIGURATION

The MB88346L has a 12-bit shift register for chip control functions. The 12-bit shift register must be used to set up data in the configuration shown below.

The data configuration has a total of 12 bits, four for address selection and eight for D/A data output.

1. Shift Register Control Data Configuration



2. D/A Converter Control Signals

| D0 | D1 | D2 | D3 | D4 | D5 | D6 | D7 | D/A data output |
|----|----|----|----|----|----|----|----|---|
| 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | ≅ Vss |
| 1 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | ≅ VLB+ VSS |
| 0 | 1 | 0 | 0 | 0 | 0 | 0 | 0 | ≅ VLB × 2 + VSS |
| • | • | • | • | • | • | • | • | • |
| • | • | • | • | • | • | • | • | • |
| 0 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | ≅ V _{LB} × 254 + V _{SS} |
| 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | ≅ Vdd |

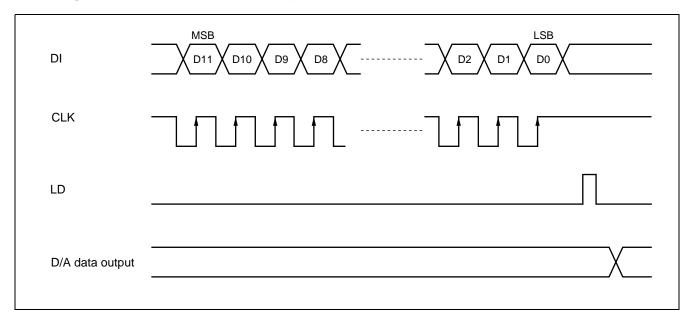
VLB = (VDD - VSS)/255

3. Address Selection Signals

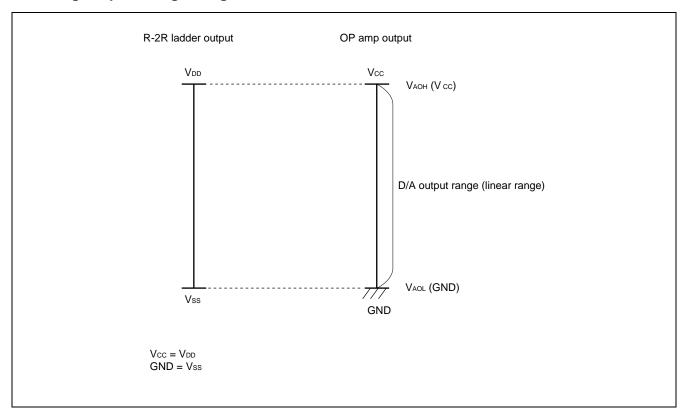
| D8 | D9 | D10 | D11 | Address selection |
|----|----|-----|-----|----------------------------|
| 0 | 0 | 0 | 0 | Don't Care |
| 0 | 0 | 0 | 1 | AO ₁ selection |
| 0 | 0 | 1 | 0 | AO ₂ selection |
| 0 | 0 | 1 | 1 | AO ₃ selection |
| 0 | 1 | 0 | 0 | AO ₄ selection |
| 0 | 1 | 0 | 1 | AO ₅ selection |
| 0 | 1 | 1 | 0 | AO6 selection |
| 0 | 1 | 1 | 1 | AO ₇ selection |
| 1 | 0 | 0 | 0 | AO ₈ selection |
| 1 | 0 | 0 | 1 | AO ₉ selection |
| 1 | 0 | 1 | 0 | AO ₁₀ selection |
| 1 | 0 | 1 | 1 | AO ₁₁ selection |
| 1 | 1 | 0 | 0 | AO ₁₂ selection |
| 1 | 1 | 0 | 1 | Don't Care |
| 1 | 1 | 1 | 0 | Don't Care |
| 1 | 1 | 1 | 1 | Don't Care |

■ OPERATING DESCRIPTION

1. Timing Chart for Data Condition Setup



2. Analog Output Voltage Range



■ ABSOLUTE MAXIMUM RATINGS

| Prameter | Symbol | Condition | Rat | Unit | | |
|-----------------------|--------|------------------------|-----------------|-----------|-------|--|
| Frameter | Symbol | Condition | Min. | Max. | Oilit | |
| Dower cumply voltage | Vcc | | -0.3 | +7.0 | V | |
| Power supply voltage | VDD* | GND used as reference, | -0.3 | +7.0 | V | |
| Input voltage | Vin | Ta = 25°C | -0.3 | Vcc + 0.3 | V | |
| Output voltage | Vouт | | -0.3 | Vcc + 0.3 | V | |
| Power consumption | PD | _ | _ | 250 | mW | |
| Operating temperature | Та | _ | -20 | +85 | °C | |
| Storage temperature | Tstg | _ | - 55 | +150 | °C | |

^{*:} Vcc ≥Vdd

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

■ RECOMMENDED OPERATING CONDITIONS

| Prameter | Symbol | Condition | | Unit | | | |
|-------------------------------------|----------|---|------|------|-----------|----|--|
| Frameter | Syllibol | Condition | Min. | Тур. | Max. | 0 | |
| Power supply voltage 1 | Vcc | _ | 2.7 | _ | 3.6 | V | |
| Power supply voltage 1 | GND | _ | _ | 0 | _ | V | |
| Power supply voltage 2 | VDD | V _{DD} – V _{SS} ≥ 2.0 V | 2.0 | _ | Vcc | V | |
| Power supply voltage 2 | Vss | VDD - VSS ≥ 2.0 V | GND | _ | Vcc - 2.0 | V | |
| Analog output source current | IAL | Vcc = 3.0 V | _ | _ | 1.0 | mA | |
| Analog output sink current | Іан | Vcc = 3.0 V | _ | _ | 1.0 | mA | |
| Oscillator limiting output capacity | Cal | _ | _ | _ | 0.1 | μF | |
| Digital data value range | _ | _ | #00 | _ | #FF | _ | |
| Operating temperature | Та | _ | -20 | _ | +85 | °C | |

WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representatives beforehand.

■ ELECTRICAL CHARACTERISTICS

1. DC Characteristics

(1) Digital Block

(VDD, VCC = +2.7 V to 3.6 V (VCC \geq VDD), GND = Vss = 0 V, Ta = -20° C to $+85^{\circ}$ C)

| Prameter | Symbol | Pin | Condition | | Unit | | |
|------------------------|--------|----------------|--|-----------|------|---------|-------|
| Prameter | Symbol | | Condition | Min. | Тур. | Max. | Offic |
| Power supply voltage | Vcc | | _ | 2.7 | 3.0 | 3.6 | V |
| Power supply current 1 | Icc | Vcc | Stationary (CLK signal stopped), no load | _ | 1.2 | 3.0 | mA |
| Input leak current | lilk | a =. | Vin = 0 to Vcc | -10 | _ | 10 | μΑ |
| L level input voltage | VIL | CLK, DI, LD | _ | _ | | 0.2 Vcc | V |
| H level input voltage | ViH | | _ | 0.8 Vcc | _ | _ | V |
| L level output voltage | Vol | DO | IOL = 2.5 mA | _ | | 0.4 | V |
| H level output voltage | Vон | | Іон = -400 μА | Vcc - 0.4 | _ | _ | V |

(2) Analog Block 1

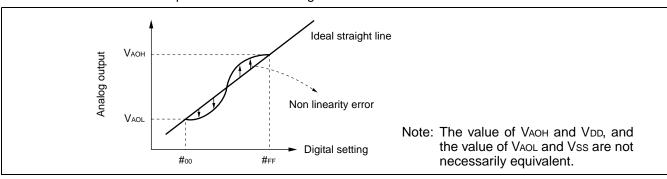
(VDD, VCC = +2.7 V to 3.6 V (VCC \geq VDD), GND = Vss = 0 V, Ta = -20° C to $+85^{\circ}$ C)

| Prameter | Symbol | Pin | Condition | | Unit | | |
|------------------------------|--------|--------------------|---|------|------|-----------|-------|
| Frameter | Symbol | | Condition | Min. | Тур. | Max. | Oilit |
| Power consumption | ldd | Vdd | Maximum setting value from #00 to #FF | _ | 0.6 | 1.5 | mA |
| Analog voltage | Vdd | Vdd | V _{DD} – Vss ≥ 2.0 | 2.0 | _ | Vcc | V |
| Analog voltage | Vss | Vss | VDD - VSS ≥ 2.0 | GND | _ | Vcc - 2.0 | V |
| Resolution | Res | | _ | _ | 8 | _ | bits |
| Monotonic increase | Rem | AO ₁ to | | _ | 8 | _ | bits |
| Nonlinearity error | LE | AO ₁₂ | $V_{DD} \le V_{CC} - 0.1 \text{ V},$ $V_{SS} \ge 0.1 \text{ V}, \text{ no load}$ | -1.5 | _ | 1.5 | LSB |
| Differential linearity error | DLE | | | -1.0 | _ | 1.0 | LSB |

Nonlinearity error:

Deviation (error) in input/output curves with respect to an ideal straight line connecting output voltage at "00" and output voltage at "FF."

Differential linearity error: Deviation (error) in amplification with respect to theoretical increase in amplification per 1-bit increase in digital value.



(3) Analog Block 2

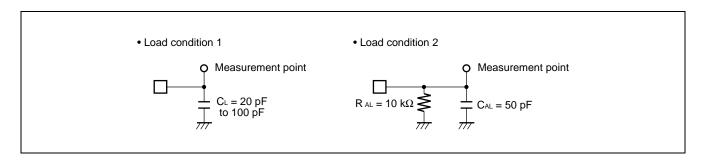
(VDD, VCC = +2.7 V to 3.6 V (VCC \geq VDD), GND = Vss = 0 V, Ta = -20° C to $+85^{\circ}$ C)

| Dromotor | <u> </u> | | 7 V to 3.6 V (VCC ≥ VDD | | Value | | | |
|-----------------------------|----------|----------------|---|-----------------------|-------|-----------|------|--|
| Prameter | Symbol | PIII | Pin Condition | | Тур. | Max. | Unit | |
| Output minimum voltage 1 | VAOL1 | | $\begin{aligned} \text{VDD} &= \text{Vcc} = 3.0 \text{ V,} \\ \text{Vss} &= \text{GND} = 0.0 \text{ V,} \\ \text{IAL} &= 0 \mu\text{A} \\ \text{Digital data} &= \#00 \end{aligned}$ | Vss | _ | Vss + 0.1 | V | |
| Output minimum voltage 2 | VAOL2 | | $\label{eq:decomposition} \begin{array}{l} \text{VDD} = \text{Vcc} = 3.0 \text{ V,} \\ \text{Vss} = \text{GND} = 0.0 \text{ V,} \\ \text{IAL} = 500 \mu\text{A} \\ \text{Digital data} = \#00 \end{array}$ | Vss - 0.2 | Vss | Vss + 0.2 | V | |
| Output minimum voltage 3 | VAOL3 | | $\begin{array}{l} \text{VDD} = \text{VCC} = 3.0 \text{ V,} \\ \text{Vss} = \text{GND} = 0.0 \text{ V,} \\ \text{IAH} = 500 \ \mu\text{A} \\ \text{Digital data} = \#00 \end{array}$ | Vss | _ | Vss + 0.2 | V | |
| Output minimum voltage 4 | VAOL4 | AO1 to AO12 | VDD = VCC = 3.0 V, Vss = GND = 0.0 V, IAL = 1.0 mA Digital data = #00 | Vss - 0.3 | Vss | Vss + 0.3 | V | |
| Output minimum voltage 5 | Vaol5 | | VDD = VCC = 3.0 V, Vss = GND = 0.0 V IAH = 1.0 mA Digital data = #00 | Vss | _ | Vss + 0.3 | V | |
| Output maximum voltage 1 | Vaoh1 | | $\begin{aligned} &\text{VDD} = \text{Vcc} = 3.0 \text{ V,} \\ &\text{Vss} = \text{GND} = 0.0 \text{ V,} \\ &\text{IAL} = 0 \mu\text{A} \\ &\text{Digital data} = \#\text{FF} \end{aligned}$ | V _{DD} - 0.1 | _ | VDD | V | |
| Output maximum voltage 2 | Vаон2 | | $\begin{aligned} \text{VDD} &= \text{Vcc} = 3.0 \text{ V,} \\ \text{Vss} &= \text{GND} = 0.0 \text{ V,} \\ \text{IAL} &= 500 \mu\text{A} \\ \text{Digital data} &= \#\text{FF} \end{aligned}$ | V _{DD} - 0.2 | _ | VDD | V | |
| Output maximum voltage 3 | Vаонз | | $\begin{array}{l} \text{VDD} = \text{Vcc} = 3.0 \text{ V,} \\ \text{Vss} = \text{GND} = 0.0 \text{ V,} \\ \text{IAH} = 500 \ \mu\text{A} \\ \text{Digital data} = \#\text{FF} \end{array}$ | V _{DD} - 0.2 | Vdd | VDD + 0.2 | V | |
| Output maximum voltage 4 | VаОн4 | | V _{DD} = V _{CC} = 3.0 V, V _{SS} = GND = 0.0 V, I _{AL} = 1.0 mA Digital data = #FF | V _{DD} - 0.3 | _ | VDD | V | |
| Output maximum voltage 5 | Vaoh5 | | VDD = Vcc = 3.0 V, Vss = GND = 0.0 V, IAH = 1.0 mA Digital data = #FF | VDD - 0.3 | Vdd | Vpp + 0.3 | V | |

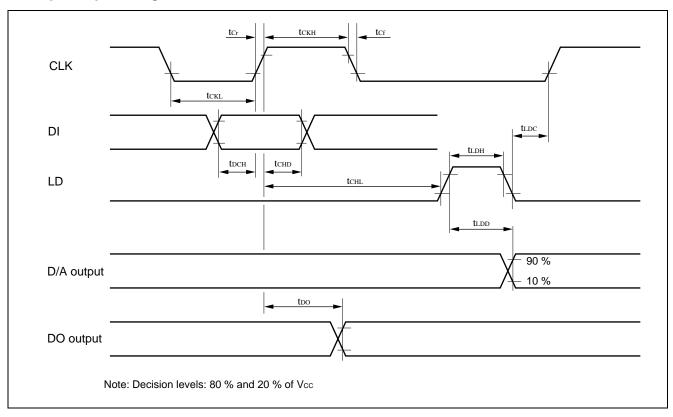
2. AC Characteristics

(VDD, VCC = +2.7 V to 3.6 V (VCC \geq VDD), GND = Vss = 0 V, Ta = -20°C to +85°C)

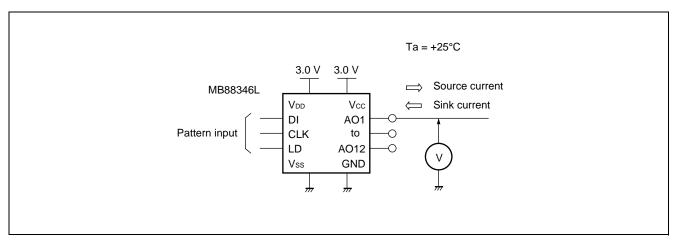
| Prameter | Symbol | Condition | Va | Unit | |
|------------------------------------|------------|--------------------------|------|------|-------|
| Frameter | Syllibol | Condition | Min. | Max. | Offic |
| Clock L level pulse width | tckl | _ | 200 | _ | ns |
| Clock H level pulse width | tскн | _ | 200 | _ | ns |
| Clock rise time Clock fall time | tCr tCf | _ | _ | 200 | ns |
| Data setup time | toch | _ | 30 | _ | ns |
| Data hold time | tchd | _ | 60 | _ | ns |
| Load setup time | tchl | _ | 200 | _ | ns |
| Load hold time | tldc | _ | 100 | _ | ns |
| Load H level pulse width | tldh | _ | 100 | _ | ns |
| Data output delay time | too | See "• Load condition 1" | 70 | 600 | ns |
| D/A output settling time | tldd | See "• Load condition 2" | _ | 300 | μs |

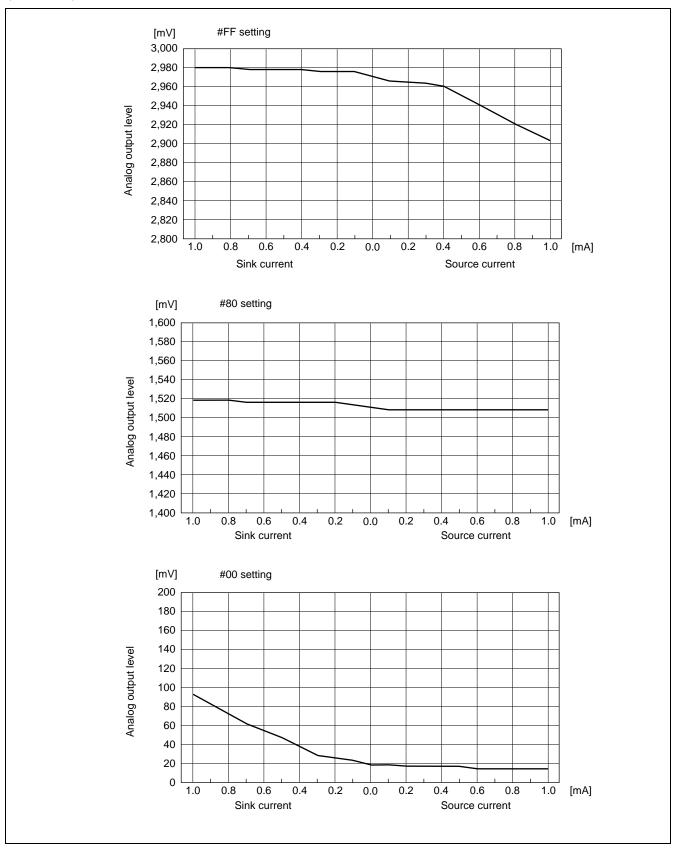


• Input/output timing



■ Vao vs. Iao CHARACTERISTICS: EXAMPLE

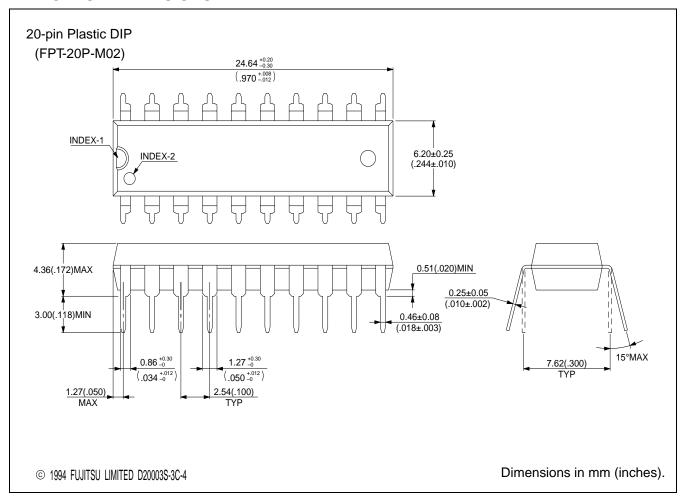


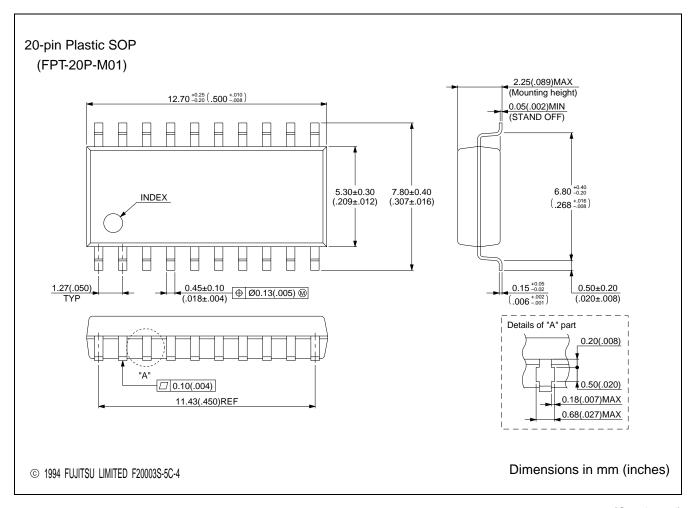


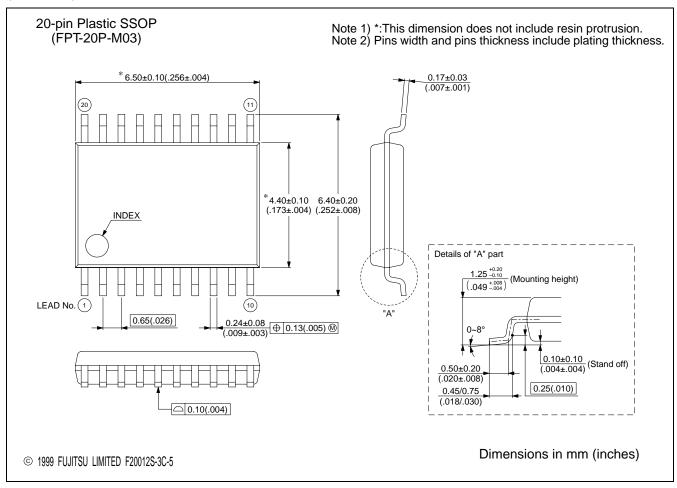
■ ORDERING INFORMATION

| Part number | Package | Remarks |
|-------------|--------------------------------------|---------|
| MB88346LP | 20-pin Plastic DIP (DIP-20P-M02) | |
| MB88346LPF | 20-pin Plastic SOP (FPT-20P-M01) | |
| MB88346LPFV | 20-pin Plastic SSOP (FPT-20P-M03) | |

■ PACKAGE DIMENSIONS







FUJITSU LIMITED

For further information please contact:

Japan

FUJITSU LIMITED

Corporate Global Business Support Division

Electronic Devices

KAWASAKI PLANT, 4-1-1, Kamikodanaka,

Nakahara-ku, Kawasaki-shi, Kanagawa 211-8588, Japan

Tel: +81-44-754-3763 Fax: +81-44-754-3329

http://www.fujitsu.co.jp/

North and South America

FUJITSU MICROELECTRONICS, INC.

3545 North First Street,

San Jose, CA 95134-1804, USA

Tel: +1-408-922-9000 Fax: +1-408-922-9179

Customer Response Center

Mon. - Fri.: 7 am - 5 pm (PST)

Tel: +1-800-866-8608 Fax: +1-408-922-9179

http://www.fujitsumicro.com/

Europe

FUJITSU MICROELECTRONICS EUROPE GmbH

Am Siebenstein 6-10,

D-63303 Dreieich-Buchschlag,

Germany

Tel: +49-6103-690-0 Fax: +49-6103-690-122

http://www.fujitsu-fme.com/

Asia Pacific

FUJITSU MICROELECTRONICS ASIA PTE LTD

#05-08, 151 Lorong Chuan,

New Tech Park, Singapore 556741 Tel: +65-281-0770

Fax: +65-281-0220

http://www.fmap.com.sg/

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